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FAIRCHILD March 2016 **MJD122 NPN Silicon Darlington Transistor Features** Equivalent Circuit D-PAK for Surface Mount Applications High DC Current Gain • Built-in a Damper Diode at E-C Lead Formed for Surface Mount Applications Electrically Similar to Popular TIP122 D-PAK Complement to MJD127 1.Base 2.Collector 3.Emitter R1 R2 $\begin{array}{l} R1 \cong 8k\Omega \\ R2 \cong 0.12k\Omega \end{array}$ F

Ordering Information

Part Number	Top Mark	Package	Packing Method
MJD122TF	MJD122	TO-252 3L (DPAK)	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5	V
۱ _C	Collector Current (DC)	8	А
I _{CP}	Collector Current (Pulse)	16	Α
I _B	Base Current	120	mA
D.	Collector Dissipation ($T_C = 25^{\circ}C$)	20	W
P _C	Collector Dissipation ($T_A = 25^{\circ}C$)	1.75	W
ТJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 to 150	°C

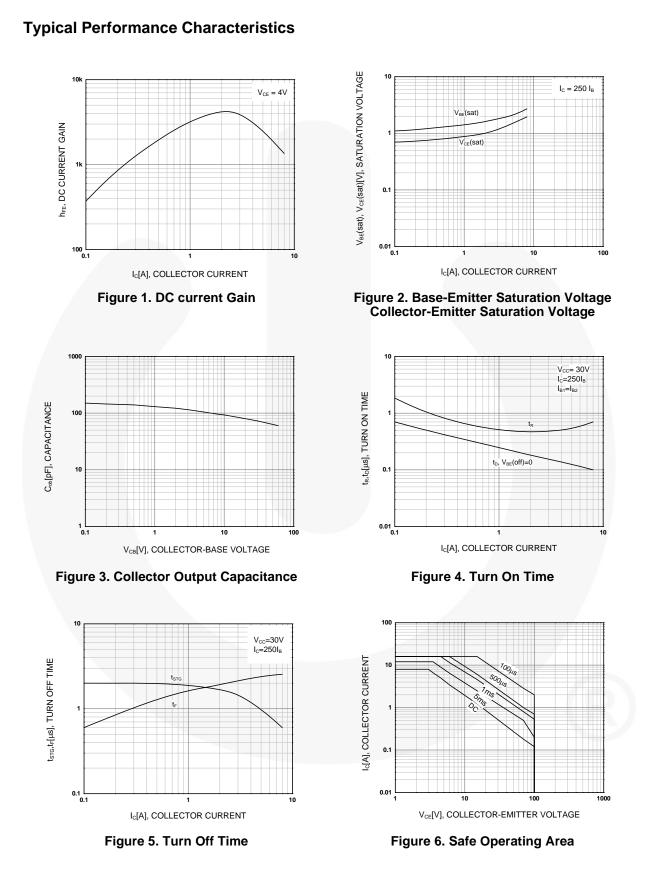
Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

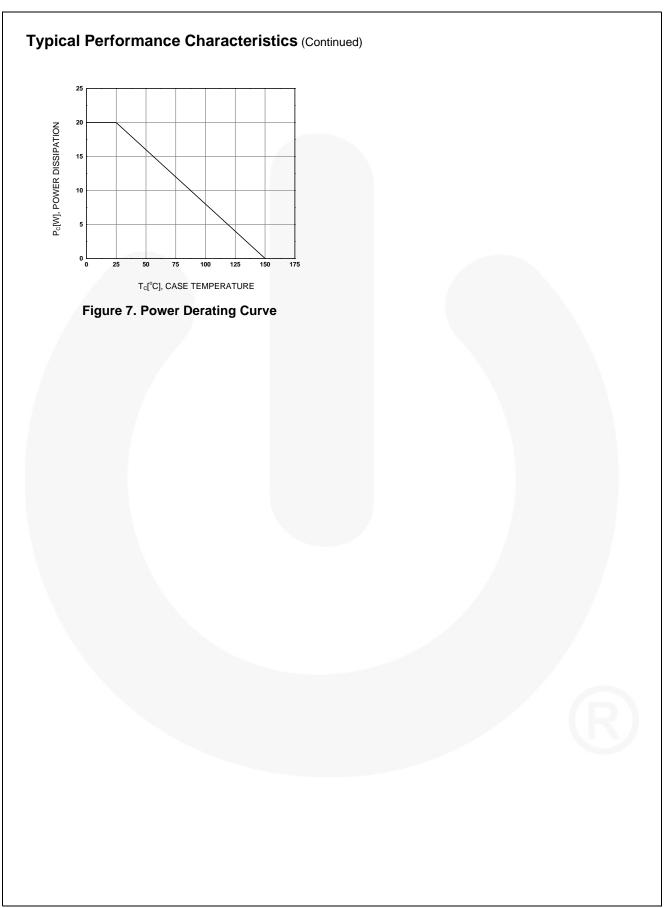
Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage ⁽¹⁾	I _C = 30 mA, I _B = 0	100		V
I _{CEO}	Collector Cut-off Current	$V_{CE} = 50 \text{ V}, \text{ I}_{B} = 0$		10	μA
I _{CBO}	Collector Cut-off Current	$V_{CB} = 100 \text{ V}, I_{E} = 0$		10	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5 V, I_{C} = 0$		2	mA
h _{FE}	DC Current Gain ⁽¹⁾	$V_{CE} = 4 \text{ V}, I_C = 4 \text{ A}$ $V_{CE} = 4 \text{ V}, I_C = 8 \text{ A}$	1000 100	12K	
V _{CE} (sat)	Collector-Emitter Saturation Voltage ⁽¹⁾	$I_{C} = 4 \text{ A}, I_{B} = 16 \text{ mA}$ $I_{C} = 8 \text{ A}, I_{B} = 80 \text{ mA}$		2 4	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage ⁽¹⁾	I _C = 8 A, I _B = 80 mA		4.5	V
V _{BE} (on)	Base-Emitter On Voltage ⁽¹⁾	$V_{CE} = 4 \text{ V}, \text{ I}_{C} = 4 \text{ A}$		2.8	V
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0$ f= 0.1MHz		200	pF

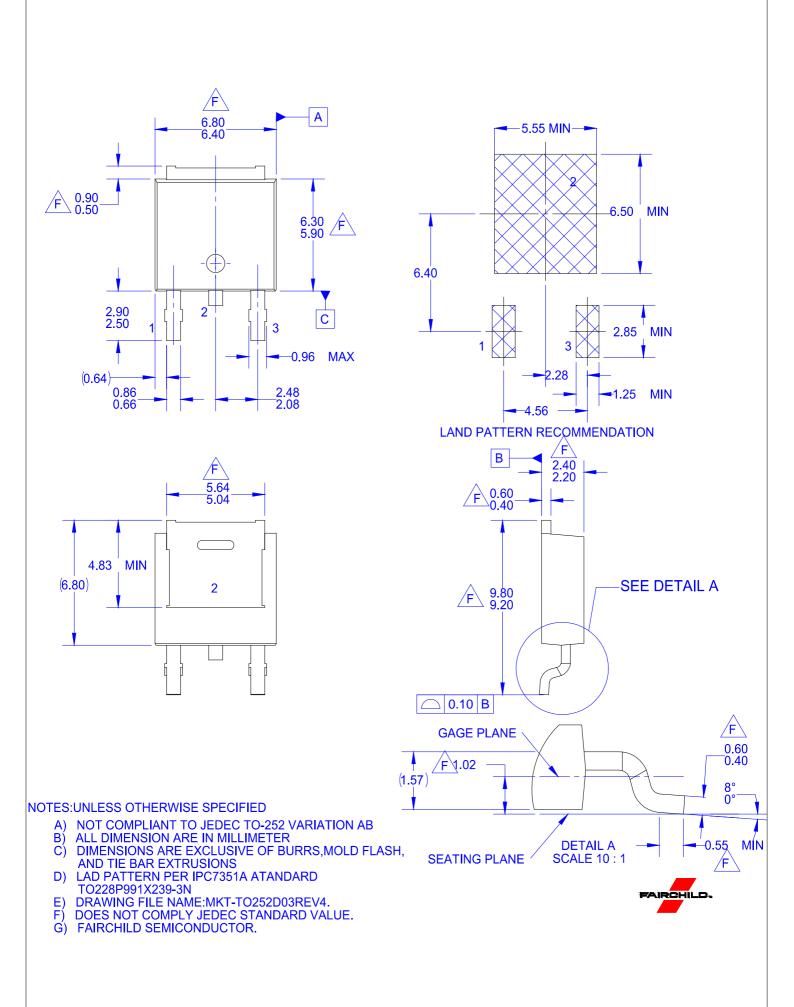
Note:

1. Pulse test: pw \leq 300 $\mu s,$ duty cycle \leq 2%.



MJD122 — NPN Silicon Darlington Transistor





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